

# Low voltage PNP power transistor

#### **Features**

- Low saturation voltage
- PNP transistor

## **Applications**

■ Audio, power linear and switching applications

### **Description**

The device is manufactured in planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The NPN type is BD237.

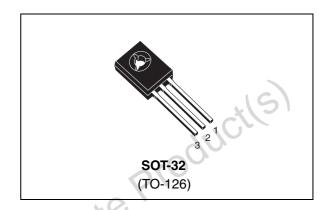


Figure 1. Internal schematic diagram

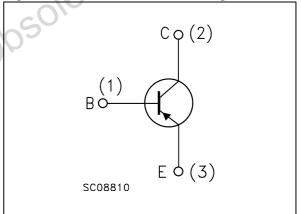


Table 1. Device summary

Order code	Marking	Package	Packaging
BD238	BD238	SOT-32	Tube

June 2009 Doc ID 15786 Rev 1 1/9

# 1 Absolute maximum ratings

Table 2. Absolute maximum ratings

$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Symbol	Parameter	Value	Unit
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$V_{CBO}$	Collector-base voltage (I <sub>E</sub> = 0)	-100	V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V <sub>CER</sub>	Collector-emitter voltage (R <sub>BE</sub> = 1 kΩ)	-100	V
$I_C$ Collector current     -2     A $I_{CM}$ Collector peak current ( $t_p < ms$ )     -6     A $P_{TOT}$ Total dissipation at $T_{case} = 25$ °C     25     W	V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	-80	V
$I_{CM}$ Collector peak current ( $t_p < ms$ )     -6     A $P_{TOT}$ Total dissipation at $T_{case} = 25  ^{\circ}C$ 25     W	V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	-5	V
P <sub>TOT</sub> Total dissipation at T <sub>case</sub> = 25 °C 25 W	I <sub>C</sub>	Collector current	-2	Α
	I <sub>CM</sub>	Collector peak current (t <sub>p</sub> < ms)	-6	Α
T <sub>stg</sub> Storage temperature -65 to 150 °C  T <sub>J</sub> Max. operating junction temperature 150 °C	P <sub>TOT</sub>	Total dissipation at T <sub>case</sub> = 25 °C	25	W
T <sub>J</sub> Max. operating junction temperature 150 °C	T <sub>stg</sub>	Storage temperature	-65 to 150	°C
aduct(s) Obsolete	TJ	Max operating junction temperature	150	°C
		Olosoleite		

## 2 Electrical characteristics

(T<sub>case</sub> = 25 °C; unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	$V_{CB} = -100 \text{ V}$ $V_{CB} = -100 \text{ V T}_{c} = 150 \text{ °C}$		-	-0.1 -2	mA mA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -5 V		-	-1	mA
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -100 mA	-80	JU!C		V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = -1 A I <sub>B</sub> = -0.1 A	(0)	-	-0.6	V
V <sub>BE(on)</sub> <sup>(1)</sup>	Base-emitter on voltage	$I_C = -1 A$ $V_{CE} = -2 V$		-	-1.3	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = -150 \text{ mA}$ $V_{CE} = -2 \text{ V}$ $I_C = -1 \text{ A}$ $V_{CE} = -2 \text{ V}$	40 25	-		

<sup>1.</sup> Pulsed duration = 300 μs, duty cycle = 1.5 %.

Electrical characteristics BD238

## 2.1 Electrical characteristic (curves)

Figure 2. Safe operating area

Figure 3. Derating curves

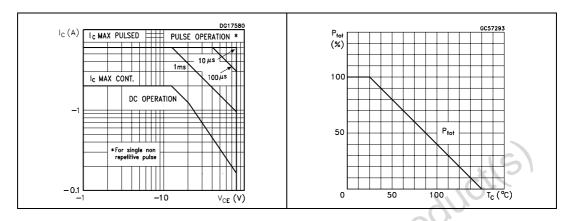


Figure 4. DC current gain ( $V_{CE} = -2 \text{ V}$ ) Figure 5. DC current gain ( $V_{CE} = -4 \text{ V}$ )

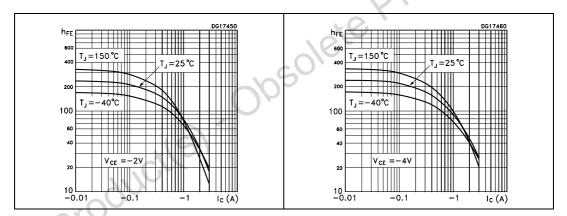
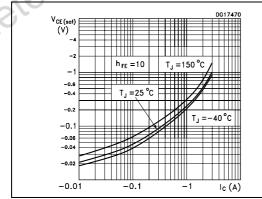


Figure 6. Collector-emitter saturation Figure 7. Base-emitter saturation voltage



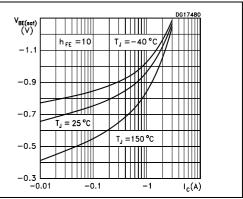
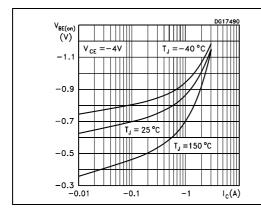


Figure 8. Base-emitter on voltage

Figure 9. Resistive load switching time (on)



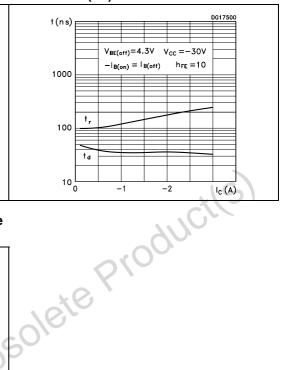
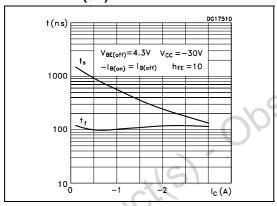
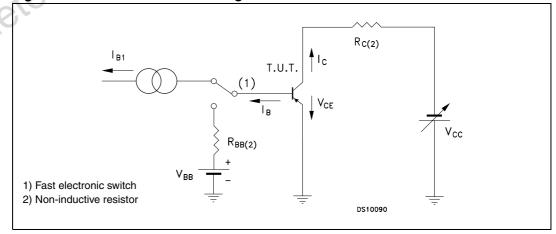


Figure 10. Resistive load switching time (off)



## 2.2 Test circuit

Figure 11. Resistive load switching test circuit



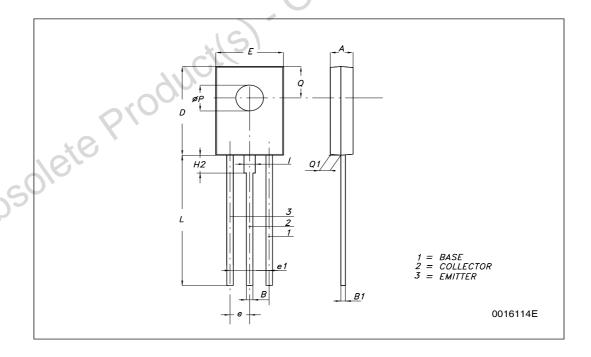
# 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.



#### SOT-32 (TO-126) mechanical data

DIM.	mm.			
DIWI.	MIN.	ТҮР	MAX.	
Α	2.4		2.9	
В	0.64		0.88	
B1	0.39		0.63	
D	10.5		11.05	
Е	7.4		7.8	
е	2.04	2.29	2.54	
e1	4.07	4.58	5.08	
L	15.3		16	
Р	2.9		3.2	
Q		3.8		
Q1	1	1/0	1.52	
H2		2.15		
I		1.27		



**577** 

Revision History BD238

# 4 Revision History

Table 4. Document revision history

Date	Revision	Changes
03-Jun-2009	1	Initial release



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